NSN 5961-01-276-0497

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View Online at https://aerobasegroup.com/nsn/5961-01-276-0497 **Inclosure Material:** Metal **Overall Length:** Between 1.365 inches and 1.387 inches **Overall Height:** Between 0.280 inches and 0.450 inches **Mounting Facility Quantity:** 2 **Internal Configuration:** Field effect Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-3 **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 500.0 breakdown voltage, drain-to-source, with all other terminals short-circuited to source and 20.0 breakdown voltage, gate-to-source, with all other terminals short-circuited to source **Current Rating Per Characteristic:** 9.60 amperes average forward current averaged over a full 60-hz cycle and 8.60 amperes on-state drain current **Power Rating Per Characteristic:** 125.0 watts total device dissipation **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: